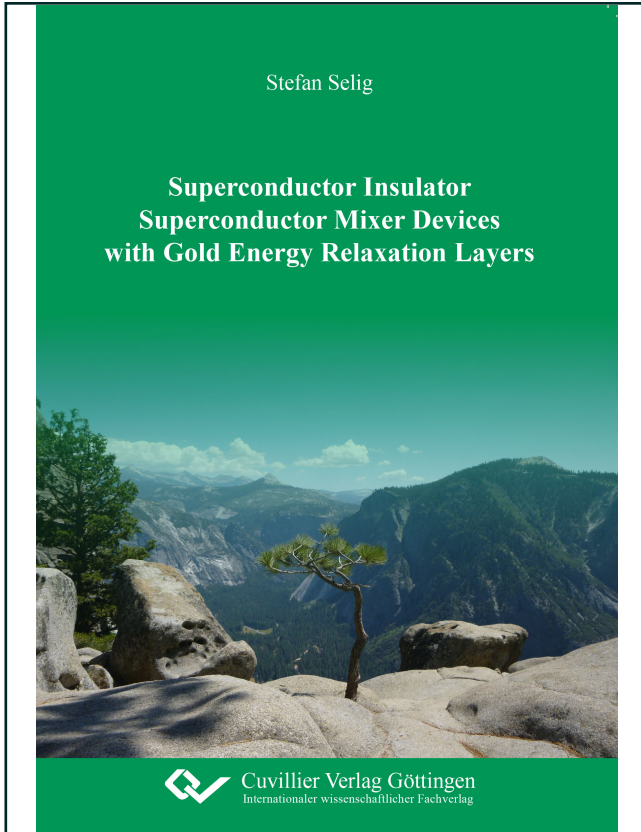




Stefan Selig (Autor)

**Superconductor Insulator Superconductor Mixer Devices with
Gold Energy Relaxation Layers**



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